## **Bipolar Transistor**

# multicomp



#### **Description:**

Plastic PNP TO-220 silicon power transistor is designed for various specific and general purpose applications such as output and driver stages of amplifiers operating at frequencies from DC to greater than 1MHz series shunt and switching regulators low and high frequency inverters/ converters and many others.

#### Features:

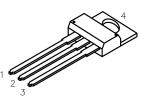
- · Very low collector saturation voltage
- Excellent linearity
- Fast switching

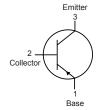
Parameter	Symbol	Rating	Unit	
Collector-Emitter Voltage	V <sub>CEO</sub>	120		
Collector-Base Voltage	V <sub>CES</sub>	120 V		
Emitter-Base Voltage	V <sub>EBO</sub>	5		
Continuous Collector Current	I <sub>c</sub>	10	А	
Base Current	I <sub>B</sub>	2	А	
Total Device Dissipation at T <sub>c</sub> = 25°C Derate above 25°C	P <sub>D</sub>	50 0.4	W W/°C	
Operating and Storage Junction Temperature Range	T <sub>j</sub> , T <sub>stg</sub>	T <sub>j</sub> , T <sub>stg</sub> -55 to +150		

#### **Absolute Maximum Ratings**

### RoHS Compliant







#### Pin Configuration:

- 1. Base
- 2. Collector
- 3. Emitter
- 4. Collector

#### Electrical Characteristics (T<sub>a</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min.	Max.	Unit		
OFF Characteristics			,				
Collector - Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	V <sub>(BR)CEO</sub> I <sub>C</sub> =30mA, I <sub>B</sub> =0		-	V		
Collector Cut-Off Current	I <sub>CES</sub>	V <sub>CE</sub> =45V, V <sub>BE</sub> =0	-	10	μA		
Emitter Cut-Off Current	I <sub>EBO</sub>	$V_{EB}$ =5V, I <sub>C</sub> =0	-	100			
ON Characteristics							
DC Current Gain	h	V <sub>CE</sub> =1V, I <sub>C</sub> =2A	35	-	-		
	h <sub>FE</sub>	V <sub>CE</sub> =1V, I <sub>C</sub> =4A	20	-	-		
Collector - Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =8A, I <sub>B</sub> =800mA	-	1	V		
Base - Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =8A, I <sub>B</sub> =800mA		1.5			

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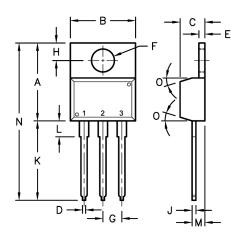


## **Bipolar Transistor**



#### Electrical Characteristics (T<sub>a</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min.	Max.	Unit
Small-Signal Characteristics					
Current Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =500mA, f=0.5MHz	12	-	MHz
Output Capacitance	C <sub>obo</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz	400	-	pF
Switching Characteristics					
Rise Time	t <sub>r</sub>		-	0.6	
Storage Time	t <sub>s</sub>	I <sub>C</sub> =5A, I <sub>B1</sub> =I <sub>B2</sub> =500mA	-	1.2	μA
Fall Time	t <sub>f</sub>		-	0.5	



#### **Pin Configuration:**

- 1. Base
- 2. Collector
- 3. Emitter

	Dimensions	А	В	С	D	E	F	G	Н	J	K	L	М	Ν	0
	Min.	14.42	9.63	3.65	-	1.15	3.75	2.29	2.54	-	12.7	2.8	2.03	-	<b>7</b> °
Γ	Max.	16.51	10.67	4.83	0.9	1.4	3.88	2.79	3.43	0.56	14.73	4.07	2.92	31.24	1

**Dimensions : Millimetres** 

#### Part Number Table

Description	Part Number				
Transistor, PNP, 8A, 120V, TO-220	MJE15029				

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